PNP/NPN Epitaxial Planar Silicon Transistors



2SA1518/2SC3912

Switching Applications (With Bias Resistance)

Application

· Switching circuits, inverters circuits, inferface circuits, driver circuits.

Features

· On-chip bias resistance : R1=10k Ω , R2=10k Ω .

· Small-sized package : CP.

· Large current capacity: I_C=500mA.

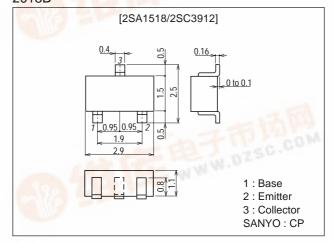
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Specifications

Absolute Maximum Ratings at Ta = 25°C

Package Dimensions

unit:mm 2018B



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)50	V
Collector-to-Emitter Voltage	V _{CEO}		(-)50	V
Emitter-to-Base Voltage	V _{EBO}	The state of the s	(–)10	V
Collector Current	I _C		(-)500	mA
Peak Collector Current	lCP		(-)800	mA
Collector Dissipation	PC	ATTA 7 CA 1-5	200	mW
Junction Temperature	Tj	00//0	150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)40V, I _E =0			(-)0.1	μΑ
	ICEO	V _{CE} =(-)40V, IB=0			(-)0.5	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)5V, I _C =0	(-)195	(-)250	(-)360	μΑ
DC Current Gain	h _{FE}	V _{CE} =(-)5V, I _C =(-)10mA	50*		40.	
Gain-Bandwidth Product	-	V _{CE} =(-)10V, I _C =(-)5mA		250		MHz
	fT		AL VI	(200)		MHz
Output Capacitance	0	V _{CB} =(-)10V, f=1MHz		3.7		pF
	C _{ob}			(5.5)		pF

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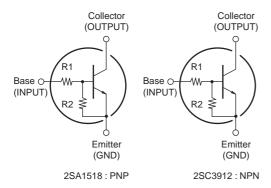
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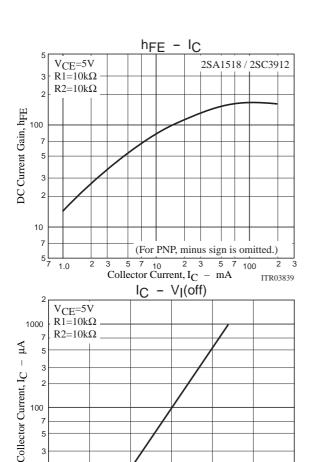
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)20mA, I _B =(-)1mA		(-)0.1	(-)0.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μA, I _E =0	(-)50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)100μA, R _{BE} =∞	(-)50			V
Input OFF-State Voltage	V _{I(off)}	$V_{CE}=(-)5V, I_{C}=(-)100\mu A$	(-)0.8	(-)1.1	(-)1.5	V
Input ON-State Voltage	V _{I(on)}	V _{CE} =(-)0.2V, I _C =(-)10mA	(-)1.0	(-)2.0	(-)4.0	V
Input Resistance	R1		7	10	13	kΩ
Resistance Ratio	R1/R2		0.9	1.0	1.1	

Marking 2SA1518 : LL, 2SC3912 : TY

Electrical Connection



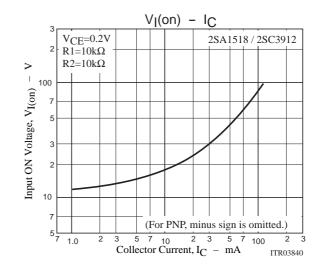


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(For PNP, minus sign is omitted.)

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